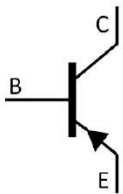


TO-92          PNP          Silicon PNP transistor in a TO-92 Plastic Package.

2SD786

Ultra-low noise, low base resistance, low noise voltage, complementary pair with 2SD786.

Ultra-low noise low-frequency amplification, low base resistance for use in MC Head amplifiers.

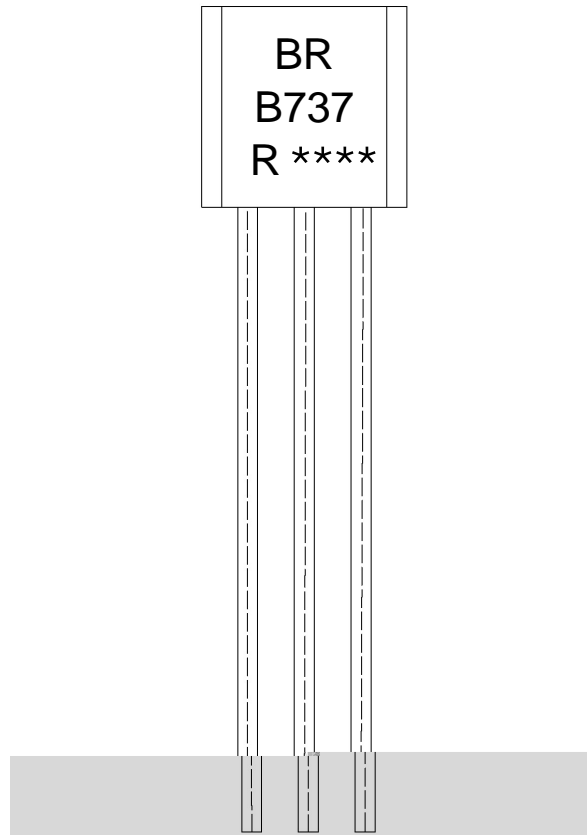


PIN1 Base          PIN 2 Collector          PIN 3 Emitter

$h_{FE}$ Classifications Symbol	Q	R	S
$h_{FE}$ Range	120~270	180~390	270~560

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	$V_{CBO}$	-50	V
Collector to Emitter Voltage	$V_{CEO}$	-40	V
Emitter to Base Voltage	$V_{EBO}$ Emitter	v	





BR:

B737

R:  $h_{FE}$

\*\*\*\*

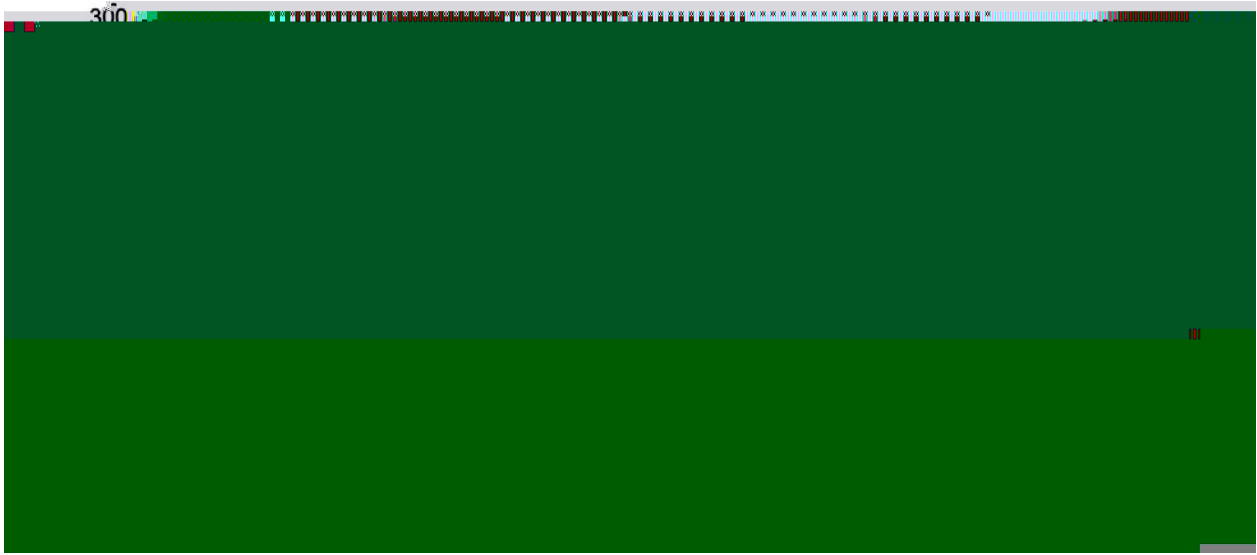
Note:

BR: Company Code.

B737: Product Type.

R:  $h_{FE}$  Classifications Symbol

\*\*\*\*: Lot No. Code,code change with Lot No.


**Note:**

- |   |        |           |   |
|---|--------|-----------|---|
| 1 | 25 150 | 60 90sec; | 1.Preheating:25~150 , Time:60~90sec.    |
| 2 | 255±5  | 5±0.5sec; | 2.Peak Temp.:255±5 , Duration:5±0.5sec. |
| 3 | 2 10   | /sec.     | 3. Cooling Speed: 2~10 /sec.            |

270±5

10±1 sec.

Temp:270±5

Time:10±1 sec

## / BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-92	1,000	10	10,000	5	50,000	135×190	237×172×102	560×245×195
	1,000	10	10,000	10	100,000	135×190	237×172×102	560×245×375

## / AMMO

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)	
	Units/tape 只/纸带	Tape/Inner Box 纸带/盒	Rows/Inner Box 纸带层/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Inner Box 盒	Outer Box 箱
TO-92	3,000	1	120	10	30,000	328×230×42	小箱 480×346×235, 大箱 547×407×268